

Optical conductivity of the type-II Weyl semimetal TaIrTe₄

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TaIrTe₄ is an example of a candidate Weyl type-II semimetal with a minimal possible number of Weyl nodes. Four nodes are reported to exist a single plane in k -space. The existence of a conical dispersion linked to Weyl nodes has yet to be shown experimentally. Here we use optical spectroscopy as a probe of the band structure on a low-energy scale. Studying optical conductivity allows us to probe intraband and interband transitions with zero momentum. In TaIrTe₄, we observe a narrow Drude contribution and an interband conductivity that may be consistent with a tilted linear band dispersion up to 40 meV. The interband conductivity allows us to establish the effective parameters of the conical dispersion; effective velocity $v = 1.1 \cdot 10^4$ m/s and tilt $\gamma = 0.37$. The transport data, Seebeck and Hall coefficients, are qualitatively consistent with conical features in the band structure. Quantitative disagreement may be linked to the multiband nature of TaIrTe₄.

Weyl semimetals are currently intensely studied both by theoretical and experimental methods. Their effective description at low energies is given by the Weyl equation, which is a variant of Dirac equation for particles with zero rest mass. This effective description results in special properties of the wave functions, leading to the appearance of pairs of Berry monopoles. The effective Weyl description also leads to a linear dispersion of energy, usually constrained to a low energy range.

The first realization of Weyl nodes in a solid came in the TaAs family. However, the band structure in that family is far from simple, and the number of nodes is very high: 24. In the past few years, efforts have been made to pinpoint a simpler realization of Weyl semimetal. Theoretically, the minimal allowed number of Weyl nodes is 4, for Weyl semimetals with broken inversion symmetry. These Weyl nodes are all located on a single plane in k -space. Arguably, TaIrTe₄ is an example of the theoretically predicted minimal Weyl semimetal, possessing only 4 Weyl nodes.^{1,2} While *ab initio* calculations predicted the existence of Weyl nodes in TaIrTe₄, surface techniques reported signatures of Fermi arcs,³ despite the challenge of Weyl cones residing above the Fermi level. A number of exotic properties have been claimed to arise in TaIrTe₄, among them are topological edge states,⁴ unconventional surface superconductivity,⁵ bulk superconductivity under pressure,⁶ large Fermi arcs reaching 1/3 of the Brillouin zone dimension,³ stretchable Weyl points and line nodes,² and circular photogalvanic effect linked to the Berry curvature.⁷

Unfortunately, many of these results hinge on the *ab initio* calculations, which become fairly unreliable at low energies on a scale of tens of milli-electron volts. One cannot trust the density functional theory (DFT) calculations to tell correctly what is the energy scale of the linear dispersion, which would be linked to the Weyl cones. Experimentally, it is difficult to expose those experimen-

tal features which are directly linked to the Weyl dispersion, particularly in the bulk properties of the candidate material. There are still only few explicit confirmations of the conical features in 3D materials such as TaIrTe₄. This is why, for TaIrTe₄, a number of questions remain unclear: Can one detect the conical dispersion and what is its scale? Where is it located with respect to the Fermi level? How much are these energy-band cones tilted?

In this work we determine the optical conductivity of TaIrTe₄. We focus in particular on its low-energy range, in order to identify the possible signatures of tilted Weyl dispersion, expected to be characteristic of this material. While one inherently cannot say anything about the Weyl character of the bands from probing the simple optical response, one can reach conclusions about the energy dispersion and its possible linearity. Weyl cones in TaIrTe₄ are of type II, meaning that they are predicted to have a certain tilt. This tilt drastically changes properties, for example it removes the electron-hole symmetry. As a result, the optical response of a tilted cone will be different than of a non-tilted cone. The tilted conical dispersion may be simply described by a 2×2 Hamiltonian matrix. From such a model, one can analytically derive various physical quantities. Specifically, here we derive the Seebeck coefficient or thermoelectric power, Hall coefficient, and the optical conductivity, in the tilted and non-tilted direction. We show, using our optical spectrum calculation for a tilted 3D conical dispersion, that even in an apparently simple situation, there is some ambiguity in the parameters that describe this dispersion. Results of our analysis are that the fingerprints of Weyl dispersion may exist on a scale of up to 40 meV.

Single crystals of TaIrTe₄ have been grown by a self-flux method. High purity starting elements in the ratio Ta:Ir:Te=1:1:25 were sealed in a quartz tube under the vacuum better than 10^{-5} mbar. The mixture was heated to 950°C (keeping it below of the boiling point of Te), al-

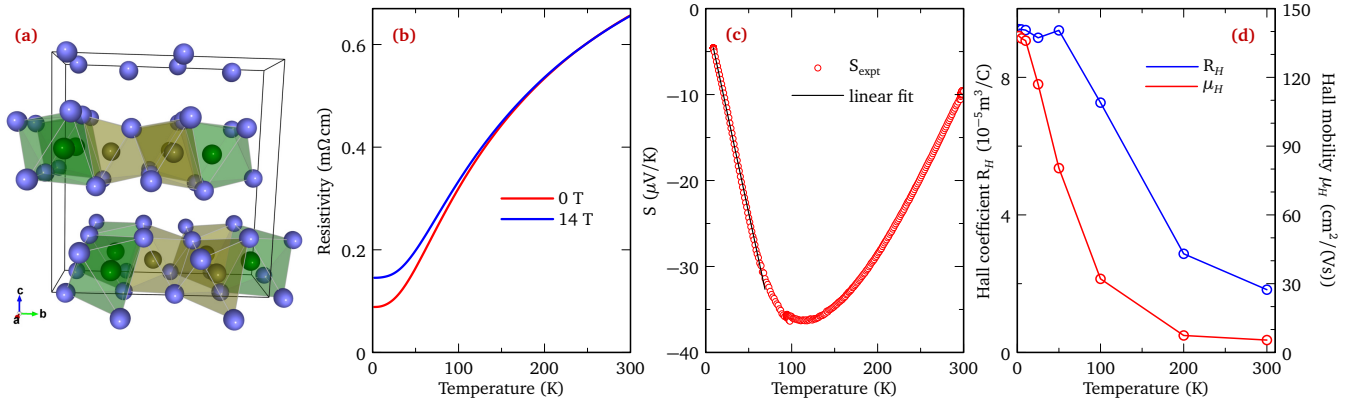


Figure 1. (a) The unit cell of TaIrTe_4 . Purple balls are tellurium atoms. The green and brown octahedra contain, respectively, tantalum and iridium atoms. The metal-metal zigzag chains run along the a axis. (b) Resistivity as a function of temperature, in zero magnetic field and in 14 T. Magnetic field is applied along the c axis. (c) Thermoelectric power or Seebeck coefficient as a function of temperature. Black line shows a linear fit below 60 K, whose slope may be used to extract the Fermi level position. (d) Hall coefficient and Hall mobility as a function of temperature.

lowing the flux to become homogeneous and slowly cooled for several days to 500°C . By centrifugation of the mixture shiny, easy to cleave, needle-like single crystals of TaIrTe_4 with the longitudinal dimension (along the b -axis) of several millimeters were obtained. Structure and composition of the crystals were confirmed using the X-ray diffraction and energy-dispersive X-ray spectroscopy. Electrical resistivity and Hall coefficient were measured in a Physical Property Measurement System from Quantum Design as a function of temperature. The sample was measured using a four-probe technique in a bar configuration in the ab -plane. Thermoelectric power was measured using a home made setup. The optical reflectivity was determined at a near-normal angle of incidence with light polarized in the ab -plane for photon energies ranging between 2 meV and 2.7 eV (16 and 22 000 cm^{-1}), at temperatures from 5 to 300 K. The single crystal was mounted on the cold finger of a He flow cryostat and absolute reflectivity was determined using the *in-situ* coating technique⁸. The complex optical conductivity was obtained using a Kramers-Kronig transformation from the reflectivity measurements. At low frequencies, we used a Hagen-Rubens extrapolation. For the high frequencies, we completed the reflectivity data using the calculated atomic X-ray scattering cross sections⁹ from 10 to 60 eV followed by a $1/\omega^4$ dependence.

The crystal structure of TaIrTe_4 is shown in Fig. 1a. Its orthorhombic structure is derived from the structure of WTe_2 , with a doubling of the b axis.¹⁰ TaIrTe_4 has the crystallographic space group $Pmn2_1$, with four formula units per unit cell.

Figure 1(b-d) shows the resistivity ρ , Seebeck coefficient S , and Hall coefficient R_H , each as a function of temperature. The resistivity in Fig. 1b is metallic, with a residual resistivity ratio $\text{RRR} = \rho(300\text{ K})/\rho(0\text{ K}) = 7.4$. This value is much smaller than in WTe_2 , but comparable to the results in literature.^{5,11} The resistivity is somewhat

enhanced in magnetic field, mostly at low temperature. The effect is much smaller than in WTe_2 ,¹² ZrTe_5 ,¹³ or in MoTe_2 .¹⁴ Although the three systems are similar to TaIrTe_4 to a certain extent, an important difference is that this compound is not nearly as close to a perfect compensation between electron and hole pockets.

The Seebeck coefficient, Fig. 1c, is negative in the entire temperature range. $S(T)$ has a specific shape given by a linear dependence at low temperatures, which is followed by a broad minimum around 120 K, and an increase towards room temperature. The linear $S(T)$ can be understood, in a first approximation, through the Mott expression which describes the diffusion of electrons in a parabolic energy band. The Mott formula relates Seebeck coefficient to the Fermi level, $S_{\text{Mott}}(T) = k_B^2 T / (e \varepsilon_F)$. Through this formula, the experimental $S(T)$ would indicate that the Fermi level is $\varepsilon_F \sim 100$ meV.

Finally, the Hall coefficient R_H , shown in Fig. 1d, has the opposite sign from the Seebeck coefficient, in agreement with the literature.¹¹ Its temperature dependence suggests an increase in the carrier density as the temperature increases. It is known that TaIrTe_4 has a complex Fermi surface, composed of two electron and two nested hole pockets.^{1,11} A multiband situation means one cannot talk about electron- or hole-dominant conduction. Fig. 1d also shows the Hall mobility, $\mu_H = \lim_{B \rightarrow 0} R_{xy} / (R_{xx} B)$. The value of μ_H is low; even at 1.8 K, it remains below $140\text{ cm}^2/(\text{Vs})$.

Overall, the transport coefficients paint a picture of TaIrTe_4 as a poor metal, characterized by fairly high values of resistivity, small RRR, high values of Seebeck coefficient, but with a metallic temperature dependence. The quantum oscillation measurements, shown in Supplementary Materials,¹⁵ confirm that the Fermi surface is made out of several pockets.¹¹ Through the transport measurements, we are able to access the intraband excitations, described by the Drude response. However, it is

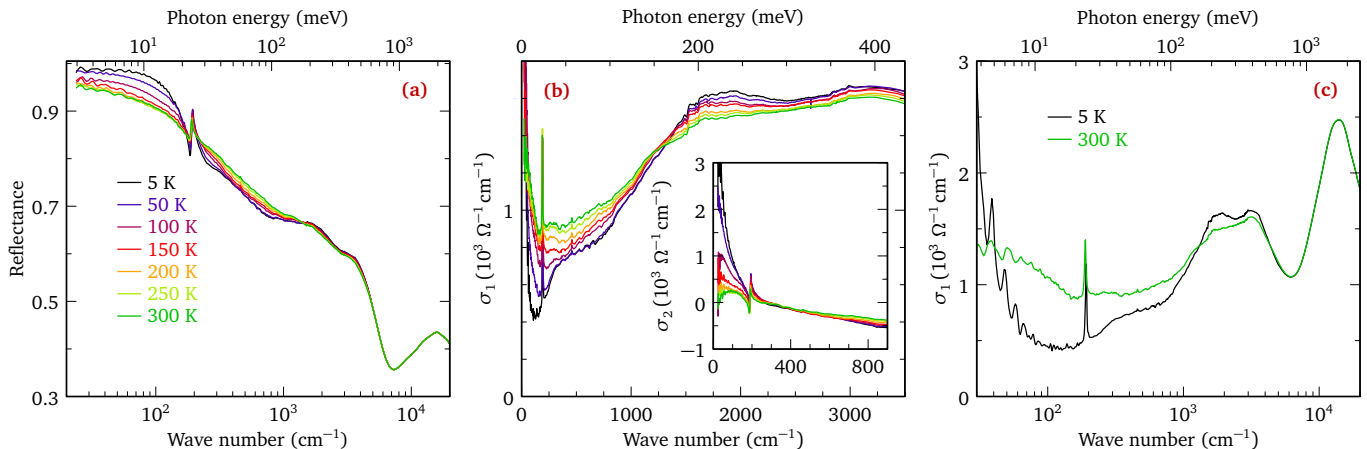


Figure 2. (a) Reflectance measured at near-normal incidence for light polarized in the *ab* plane, at several different temperatures. (b) The real part of the optical conductivity, σ_1 , as a function of incident photon energy, in the far infrared and mid infrared range (up to 400 meV), shown for the same set of temperatures as in (a). Inset shows the imaginary part of the optical conductivity, σ_2 , below 900 cm^{-1} . (c) Low- and high-temperature σ_1 as a function of incident photon energy, shown in the entire experimental range, on a logarithmic scale.

not possible based on transport alone to find the scattering rate, nor to identify if it is the carrier density, or the scattering rate, that causes most of the temperature dependence of the resistivity.

To address these questions, we resort to optical spectroscopy. The scattering rate and the carrier density are separated in the optical conductivity, as the strength and width of the Drude peak. The comparative advantage with respect to the transport measurements is not only the ability to disentangle different parameters of the Drude response, but also capability to access the excitations between different energy bands. These interband excitations directly probe the energy band dispersion through its joint density of states (JDOS).¹⁶

The reflectance of TaIrTe₄ at seven different temperatures is shown in Fig. 2a. The response is decidedly metallic, with $R \rightarrow 1$ in the low-energy limit, $\omega \rightarrow 0$. The temperature dependence is particularly strong in the far infrared range, and similar to what was observed in WTe₂ or MoTe₂.^{17,18} A single strong, sharp phonon mode is detected at 24 meV (200 cm^{-1}). Through Kramers-Kronig relations, one can determine the complex optical conductivity $\sigma = \sigma_1 + i\sigma_2$. The real part of this response function, σ_1 , leads to absorption of radiation by the material. This component is of particular interest, because it is directly proportional to the JDOS. On the contrary, the imaginary component σ_2 does not result in absorption, but only leads to a phase lag.

The real part of the optical conductivity, $\sigma_1(\omega)$, is shown in Fig. 2b for the low photon energies, and in Fig. 2c for the broad energy range. Inset of Fig. 2b shows the imaginary component, $\sigma_2(\omega)$. A narrow Drude component develops below 10 meV, associated with the free carriers. The Drude component is broader and therefore more evident in $\sigma_2(\omega)$. For example, at 300 K, a broad peak in σ_2 is centered around 100 cm^{-1} , the Drude scat-

tering rate at that temperature.

In σ_1 , low-energy interband excitations dominate the optical response between 10 and 200 meV. These excitations leave a characteristic signature which is intimately related to the JDOS, and may leave imprints of conical dispersion around the Weyl nodes. Nearly linear dependence of $\sigma_1(\omega)$ extrapolates into a finite value at $\omega = 0$. We will show later that such a finite offset is indeed expected for a tilted conical dispersion. In Fig. 2c, the high energy excitations are also visible, centered at 0.2, 0.4 and 1.8 eV. Due to the complex band structure, it is not possible to assign these excitations to specific features of the band structure.^{1,3}

Intraband excitations can be described by the Drude component, which may be characterized by a plasma frequency $\omega_{p,\text{Drude}}$ and a scattering rate $1/\tau$. The narrow Drude component in TaIrTe₄ is well distinguished in our measurements. This is seen in Fig. 3a, which shows $\sigma_1(\omega)$ in the far infrared region. The dynamical conductivity is consistent with the σ_{dc} values extracted from the resistivity measurement in Fig. 1b. The Drude component strongly narrows at low temperatures, similar to what is generally seen in similar compounds.^{16–18} The scattering rate is shown in the inset of Fig. 3c as a function of temperature. Expectedly, it increases with temperature. At low temperatures, the Drude plasma frequency is $\omega_{p,\text{Drude}} = 0.1$ eV, and the Drude scattering rate is 2.6 meV. For comparison, similarly small scattering rates $\hbar/\tau \lesssim 1$ meV were found in related compounds^{17,18} MoTe₂ and WTe₂, as well as in other candidate topological semimetals.^{16,19–21} Such a small value is characteristic of a compound with a small Fermi surface, resulting in a small *k*-space available for intraband scattering.

We distinguish three parts in σ_1 at low energies: a narrow Drude contribution, a sharp phonon contribution, and an interband part. Separating the Drude and

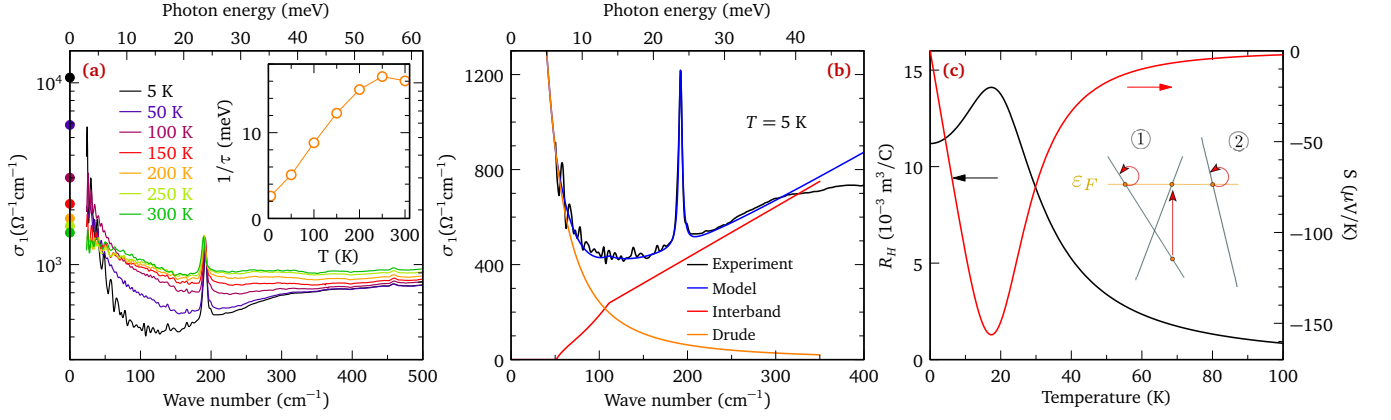


Figure 3. (a) Optical conductivity in the far infrared range, showing the Drude component. The dots represent the values of σ_{dc} determined by the measurement of the temperature dependent resistivity. Inset shows the temperature dependence of the Drude scattering rate, $1/\tau$. It is extracted from $\sigma_1(\omega)$ using a Drude-Lorentz model. (b) Decomposition of $\sigma_1(\omega)$ at 5 K into the Drude term, and an interband term. The model curve (blue) includes the Drude contribution, interband contribution from a tilted conical dispersion, and a phonon contribution. (c) Theoretically calculated Hall coefficient R_H , and Seebeck coefficient S within the tilted conical model. Inset in (c) shows a sketch of a tilted linearly dispersing band (1) and a trivial band (2); both bands cross the Fermi level. In the tilted cone, the low-energy interband transitions (vertical arrow) contribute to the optical conductivity. There is no contribution to the interband conductivity from the sketched trivial band. Both bands, however, contribute to the intraband conductivity, which is related to the measured S and R_H .

phonon contributions allows to access the interband optical response: $\sigma_{1,\text{interband}} = \sigma_1 - \sigma_{1,\text{Drude}} - \sigma_{1,\text{phonon}}$. The premise is that at low temperatures this interband response contains a signature of tilted conical dispersion linked to Weyl nodes. We perform the low energy optical analysis under certain assumptions. First, there are multiple bands at Fermi level, as inferred by DFT, but there are no interband transitions below 50 meV (400 cm^{-1}) except from those arising within the tilted cone. Second, the sum of all band contributions to the conductivity is contained in the σ_{dc} and τ of the single Drude Lorentzian. Third, the footprint of any linear-dispersion-like signature is found in the data interval from 15 to 35 meV, where we see a linear-like conductivity (see Fig. 3b).

To identify the response from a possible Weyl dispersion, a numerical calculation can be done, and the parameters used to describe the Weyl cones can be adapted to best describe the experimental optical conductivity. The Hamiltonian for a tilted Weyl cone is:

$$\hat{H}_0 = \hbar w k_z \mathcal{I} + \hbar v \mathbf{k} \cdot \boldsymbol{\sigma}, \quad (1)$$

where $\sigma_{x,y,z}$ are Pauli matrices, \mathcal{I} the identity operator, v Dirac velocity and w tilt velocity. Diagonalizing the Hamiltonian gives its eigenvalues for conduction c and valence v bands, $\varepsilon_{\mathbf{k}}^{c,v} = \hbar w k_z \pm \hbar v |\mathbf{k}|$. Using these eigenvalues one can numerically calculate the optical conductivity.¹⁵ We take into account four Weyl nodes, as given by DFT. The result is given in Fig. 3c in red and blue lines, with the following parameters: Fermi level, with respect to the tip of the cone, $\varepsilon_F = 4.3$ meV, tilt of the cone $\gamma = w/v = 0.37$, and Fermi velocity $v = 1.1 \cdot 10^4$ m/s. The parameter $\gamma < 1$ that we obtain describes an under-tilted Weyl cone. Although favoured

by the DFT, over-tilted Weyl scenario ($\gamma > 1$) would give a significantly different shape of the interband part, incompatible with experimental data.

The optical conductivity is consistent with the calculated interband conductivity within a tilted conical dispersion. This cannot be taken as a smoking gun of Weyl dispersion, as we cannot exclude other dispersions which would result in a similar interband conductivity. However, if the band structure indeed contains four Weyl cones at low energies, then our result gives their energy scale which is less than 40 meV.

The same effective Hamiltonian model can be used to calculate the Seebeck coefficient and the Hall constant. These are shown in Fig. 3c. Both are calculated assuming that $\varepsilon_F = 4.3$ meV. While there is some agreement in the temperature dependence for both coefficients, quantitatively the model overestimates both S and R_H .

Although generally a complex quantity,¹⁵ the Seebeck coefficient is simplified dramatically for a system with linear bands, when the effective Fermi velocity is constant. In such a case, $S = (1/e) \partial \mu(T) / \partial T$, where $\mu(T)$ is the chemical potential.¹⁵ This generically gives $S(T) \propto T$ at low temperatures, after which $S(T)$ reaches an extremum value, and then it decreases in absolute value. One interesting consequence of the above simple expression is that the minimum of $S(T)$ depends linearly on the Fermi energy, measured from the tip of the cone (or the Weyl node). In the case of TeIrTe_4 , the experimental thermopower (Fig. 1c) only qualitatively resembles the calculated $S(T)$, shown in Fig. 3c. The experimental minimum of $S(T)$ is observed at 100 K, and the absolute value is about 5 times smaller than in the calculation. TaIrTe_4 is a multiband system. While its optical conductivity may

well be dominated by the interband transitions arising within the tilted cones, the intraband channel will contain contributions from all the bands that cross the chemical potential, as shown in the inset of Fig. 3c. All these intraband excitations are reflected in the transport coefficients. Specifically, we see that $S(T)$ cannot be described by a simple linear-dispersion term shown in Fig. 3c, and multiband contributions lead to a smaller experimental thermopower. Similarly, R_H will be lower from what our model gives, if other bands at the Fermi level are considered, bringing it in closer agreement to the experiment.

In conclusion, we have determined the optical conductivity of a candidate type-II Weyl semimetal, TaIrTe₄. Through a combined use of detailed infrared spectroscopy and effective modelling, we show that the low-energy dynamical conductivity is broadly consistent with a tilted conical dispersion. This dispersion may explain the interband response at low energies, below 40 meV. The Fermi level may be within those conically dispersing bands.

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- ¹ K. Koepernik, D. Kasinathan, D. V. Efremov, Seunghyun Khim, Sergey Borisenko, Bernd Büchner, and Jeroen van den Brink, "TaIrTe₄: A ternary type-II Weyl semimetal," *Physical Review B* **93**, 201101– (2016).
- ² Xiaoqing Zhou, Qihang Liu, QuanSheng Wu, Tom Nummy, Haoxiang Li, Justin Griffith, Stephen Parham, Justin Waugh, Eve Emmanouilidou, Bing Shen, Oleg V. Yazyev, Ni Ni, and Daniel Dessau, "Coexistence of tunable Weyl points and topological nodal lines in ternary transition-metal telluride TaIrTe₄," *Physical Review B* **97**, 241102– (2018).
- ³ Ilya Belopolski, Peng Yu, Daniel S. Sanchez, Yukiaki Ishida, Tay-Rong Chang, Songtian S. Zhang, Su-Yang Xu, Hao Zheng, Guoqing Chang, Guang Bian, Horng-Tay Jeng, Takeshi Kondo, Hsin Lin, Zheng Liu, Shik Shin, and M. Zahid Hasan, "Signatures of a time-reversal symmetric Weyl semimetal with only four Weyl points," *Nature Communications* **8**, 942 (2017).
- ⁴ Xu Dong, Maoyuan Wang, Dayu Yan, Xianglin Peng, Ji Li, Wende Xiao, Qinsheng Wang, Junfeng Han, Jie Ma, Youguo Shi, and Yugui Yao, "Observation of Topological Edge States at the Step Edges on the Surface of Type-II Weyl Semimetal TaIrTe₄," *ACS Nano*, *ACS Nano* **13**, 9571–9577 (2019).
- ⁵ Ying Xing, Zhibin Shao, Jun Ge, Jiawei Luo, Jinhua Wang, Zengwei Zhu, Jun Liu, Yong Wang, Zhiying Zhao, Jiaqiang Yan, David Mandrus, Binghai Yan, Xiong-Jun Liu, Minghu Pan, and Jian Wang, "Surface superconductivity in the type ii weyl semimetal tairte₄," *National Science Review* (2019), 10.1093/nsr/nwz204.
- ⁶ Shu Cai, Eve Emmanouilidou, Jing Guo, Xiaodong Li, Yanchun Li, Ke Yang, Aiguo Li, Qi Wu, Ni Ni, and Liling Sun, "Observation of superconductivity in the pressurized Weyl-semimetal candidate TaIrTe₄," *Physical Review B* **99**, 020503– (2019).
- ⁷ Junchao Ma, Qiangqiang Gu, Yinan Liu, Jiawei Lai, Peng Yu, Xiao Zhuo, Zheng Liu, Jian-Hao Chen, Ji Feng, and Dong Sun, "Nonlinear photoresponse of type-II Weyl semimetals," *Nature Materials* **18**, 476–481 (2019).
- ⁸ C. C. Homes, M. Reedyk, D. A. Crandles, and T. Timusk, "Technique for measuring the reflectance of irregular, submillimeter-sized samples," *Appl. Optics* **32**, 2976 (1993).
- ⁹ D. B. Tanner, "Use of x-ray scattering functions in Kramers-Kronig analysis of reflectance," *Phys. Rev. B* **91**, 035123 (2015).
- ¹⁰ Arthur Mar, Stephane Jobic, and James A. Ibers, "Metal-metal vs tellurium-tellurium bonding in WTe₂ and its ternary variants TaIrTe₄ and NbIrTe₄," *Journal of the American Chemical Society*, *Journal of the American Chemical Society* **114**, 8963–8971 (1992).
- ¹¹ Seunghyun Khim, Klaus Koepernik, Dmitry V. Efremov, J. Klotz, T. Förster, J. Wosnitza, Mihai I. Sturza, Sabine Wurmehl, Christian Hess, Jeroen van den Brink, and Bernd Büchner, "Magnetotransport and de Haas-van Alphen measurements in the type-II Weyl semimetal TaIrTe₄," *Physical Review B* **94**, 165145– (2016).
- ¹² Mazhar N. Ali, Jun Xiong, Steven Flynn, Jing Tao, Quinn D. Gibson, Leslie M. Schoop, Tian Liang, Neel Haldolaarachchige, Max Hirschberger, N. P. Ong, and R. J. Cava, "Large, non-saturating magnetoresistance in WTe₂," *Nature* **514**, 205–208 (2014).
- ¹³ P. Shahi, D. J. Singh, J. P. Sun, L. X. Zhao, G. F. Chen, Y. Y. Lv, J. Li, J. Q. Yan, D. G. Mandrus, and J. G. Cheng, "Bipolar conduction as the possible origin of the electronic transition in pentatellurides: Metallic vs semiconducting behavior," *Physical Review X* **8**, 021055– (2018).
- ¹⁴ F. C. Chen, H. Y. Lv, X. Luo, W. J. Lu, Q. L. Pei, G. T. Lin, Y. Y. Han, X. B. Zhu, W. H. Song, and Y. P. Sun, "Extremely large magnetoresistance in the type-II Weyl semimetal MoTe₂," *Physical Review B* **94**, 235154– (2016).
- ¹⁵ In the Supplementary Materials we include additional data analysis to support our work.
- ¹⁶ E. Martino, I. Crassee, G. Eguchi, D. Santos-Cottin, R. D. Zhong, G. D. Gu, H. Berger, Z. Rukelj, M. Orlita, C. C.

- Homes, and Ana Akrap, “Two-Dimensional Conical Dispersion in ZrTe_5 Evidenced by Optical Spectroscopy,” *Phys. Rev. Lett.* **122**, 217402 (2019).
- ¹⁷ C. C. Homes, M. N. Ali, and R. J. Cava, “Optical properties of the perfectly compensated semimetal WTe_2 ,” *Phys. Rev. B* **92**, 161109 (2015).
- ¹⁸ D. Santos-Cottin, E. Martino, F. Le Mardelé, C. Witteveen, F. O. von Rohr, C. C. Homes, Z. Rukelj, and Ana Akrap, “Low-energy excitations in type-II Weyl semimetal Td-MoTe_2 evidenced through optical conductivity,” *Physical Review Materials* **4**, 021201– (2020).
- ¹⁹ A. Akrap, M. Hakl, S. Tchoumakov, I. Crassee, J. Kuba, M. O. Goerbig, C. C. Homes, O. Caha, J. Novák, F. Teppe, W. Desrat, S. Koohpayeh, L. Wu, N. P. Armitage, A. Nateprov, E. Arushanov, Q. D. Gibson, R. J. Cava, D. van der Marel, B. A. Piot, C. Faugeras, G. Martinez, M. Potemski, and M. Orlita, “Magneto-Optical Signature of Massless Kane Electrons in Cd_3As_2 ,” *Physical Review Letters* **117**, 136401– (2016).
- ²⁰ I. Crassee, E. Martino, C. C. Homes, O. Caha, J. Novák, P. Tückmantel, M. Hakl, A. Nateprov, E. Arushanov, Q. D. Gibson, R. J. Cava, S. M. Koohpayeh, K. E. Arpino, T. M. McQueen, M. Orlita, and Ana Akrap, “Nonuniform carrier density in Cd_3As_2 evidenced by optical spectroscopy,” *Physical Review B* **97**, 125204– (2018).
- ²¹ B. Xu, Y. M. Dai, L. X. Zhao, K. Wang, R. Yang, W. Zhang, J. Y. Liu, H. Xiao, G. F. Chen, A. J. Taylor, D. A. Yarotski, R. P. Prasankumar, and X. G. Qiu, “Optical spectroscopy of the Weyl semimetal TaAs ,” *Physical Review B* **93**, 121110– (2016).